

Winding Type Chip Inductor

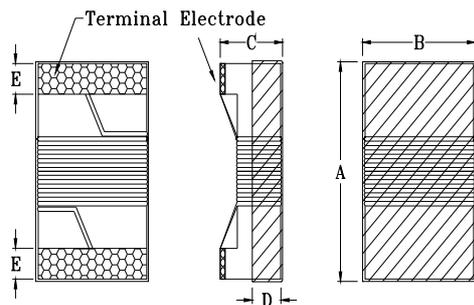
PAS3225F-102J

1. Features

1. Ferrite core wire wound construction.
2. High Reliability due to wire wound type construction.
3. Small footprint as well as low profile.
4. Application for DC power line.
5. 100% Lead(Pb) & Halogen-Free and RoHS compliant.



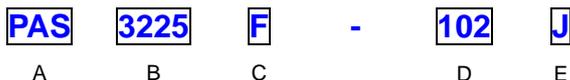
2. Dimension



Size	A	B	C	D	E
PAS3225	3.60 max.	2.80 max.	2.60 max.	0.80 ref.	0.55±0.1

Unit:mm

3. Part Numbering



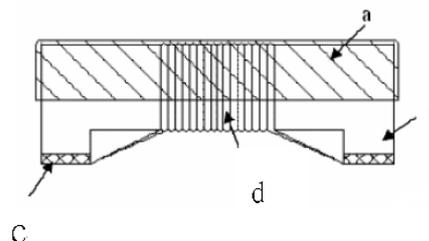
- A: Series
- B: Dimension L x W
- C: Application DC Power Line
- D: Lead free
- E: Inductance 102=1080uH
- F: Inductance Tolerance J =±5%

4. Specification

TAI-TECH Part Number	Inductance (uH)	Tolerance	Test Frequency (Hz)	Q min.	Test Frequency (KHz)	Rated Current (mA) max.	DCR (Ω) max.	SRF (MHz) min.
PAS3225F-102J	1080	J	0.1V/125K	15	125K	50	35	1.5

5. Materials

No.	Description	Specification
a.	Upper Plate	UV Glue
b.	Core	Ferrite Core
c.	Termination	Tin Pb Free
d.	Wire	Enameled Copper Wire



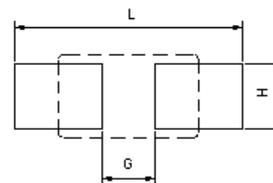
6. Reliability and Test Condition

Item	Performance	Test Condition								
Operating Temperature	-40~+125℃									
Storage Temperature(on board)										
Electrical Performance Test										
Inductance L	Refer to standard electrical characteristic list	Agilent-4291, Agilent-4287 Agilent-E4991								
Q										
SRF		Agilent-4291 Agilent-E4991								
DC Resistance		Agilent-4338								
Rated Current		Applied the current to coils, the inductance change shall be less than 20% to initial value.								
Mechanical Performance Test										
Solder Heat Resistance	<p>Appearance : No damage.</p> <p>Inductance : within±10% of initial value</p> <p>Q : Shall not exceed the specification value.</p> <p>RDC : within ±15% of initial value and shall not exceed the specification value</p>	<table border="1"> <thead> <tr> <th>Temperature (°C)</th> <th>Time (s)</th> <th>Temperature ramp/immersion and emersion rate</th> <th>Number of heat cycles</th> </tr> </thead> <tbody> <tr> <td>260 ±5 (solder temp)</td> <td>10 ±1</td> <td>25mm/s ±6 mm/s</td> <td>1</td> </tr> </tbody> </table> <p>Depth: completely cover the termination</p>	Temperature (°C)	Time (s)	Temperature ramp/immersion and emersion rate	Number of heat cycles	260 ±5 (solder temp)	10 ±1	25mm/s ±6 mm/s	1
Temperature (°C)	Time (s)	Temperature ramp/immersion and emersion rate	Number of heat cycles							
260 ±5 (solder temp)	10 ±1	25mm/s ±6 mm/s	1							
Solderability Test	More than 95% of terminal electrode should be covered with solder.	<p>Preheat: 150℃,60sec. ◦</p> <p>Solder: Sn99.5%-Cu0. 5% ◦</p> <p>Temperature: 245±5℃ ◦</p> <p>Flux for lead free: Rosin. 9.5% ◦</p> <p>Dip time: 4±1sec ◦</p> <p>Depth: completely cover the termination</p>								
Reliability Test										
Life Test		<p><u>Preconditioning:Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles</u></p> <p>Temperature : 125±2℃ (Bead)</p> <p>Temperature : 85±2℃ (Inductor)</p> <p>Applied current : rated current</p> <p>Duration : 1000±12hrs</p> <p>Measured at room temperature after placing for 24±2 hrs</p>								
Thermal shock	<p>Appearance : No damage.</p> <p>Inductance : within±10% of initial value</p> <p>Q : Shall not exceed the specification value.</p> <p>RDC : within ±15% of initial value and shall not exceed the specification value</p>	<p><u>Preconditioning:Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles</u></p> <p>Step1 : -40±2℃ 30±5min</p> <p>Step2 : 25±2℃ ≤0.5min</p> <p>Step3 : 105±2℃ 30±5min</p> <p>Number of cycles : 500</p> <p>Measured at room temperature after placing for 24±2 hrs</p>								
Humidity Resistance Test		<p><u>Preconditioning:Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles</u></p> <p>Humidity : 85±2% R.H,</p> <p>Temperature : 85℃ ±2℃</p> <p>Duration : 1000hrs Min. with 100% rated current</p> <p>Measured at room temperature after placing for 24±2 hrs</p>								
Vibration Test		<p><u>Preconditioning:Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles</u></p> <p>Oscillation Frequency: 10~2K~10Hz for 20 minutes</p> <p>Equipment : Vibration checker</p> <p>Total Amplitude:1.52mm±10%</p> <p>Testing Time : 12 hours(20 minutes, 12 cycles each of 3 orientations) ◦</p>								

7. Soldering and Mounting

7-1. Recommended PC Board Pattern

Chip size						Land Patterns For Reflow Soldering			
Series	Type	A(mm)	B(mm)	C(mm)	D(mm)	E(mm)	L(mm)	G(mm)	H(mm)
PAS	3225	3.60max	2.80max	2.60max	0.80 ref.	0.55±0.1	3.82	1.78	2.80



PC board should be designed so that products can prevent damage from mechanical stress when warping the board. Products shall be positioned in the sideways direction to against the mechanical stress to prevent failure.

7-2. Soldering

Mildly activated rosin fluxes are preferred. TAI-TECH terminations are suitable for all wave and re-flow soldering systems. If hand soldering cannot be avoided, the preferred technique is the utilization of hot air soldering tools.

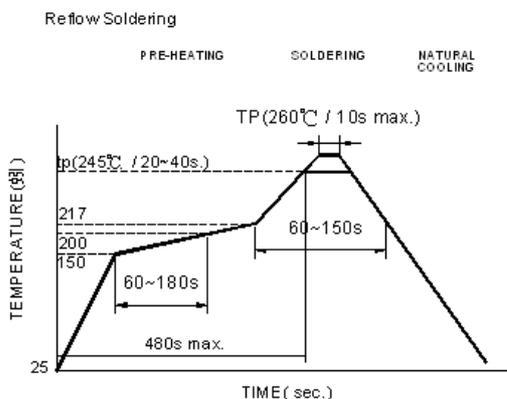
7-2.1 Solder re-flow:

Recommended temperature profiles for re-flow soldering in Figure 1.

7-2.2 Soldering Iron(Figure 2):

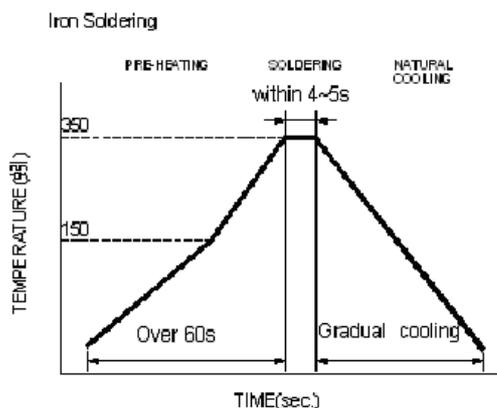
Products attachment with a soldering iron is discouraged due to the inherent process control limitations. In the event that a soldering iron must be employed the following precautions are recommended.

- Note :
- Preheat circuit and products to 150°C
 - Never contact the ceramic with the iron tip
 - Use a 20 watt soldering iron with tip diameter of 1.0mm
 - 280°C tip temperature (max)
 - 1.0mm tip diameter (max)
 - Limit soldering time to 3 sec.



Reflow times: 3 times max.

Fig.1



Iron Soldering times: 1 times max.

Fig.2

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以下測試樣品係由申請廠商所提供及確認 (The following sample(s) was/were submitted and identified by/on behalf of the applicant as) :

樣品名稱(Sample Description) : WIREWOUND SERIES
樣品型號(Style/Item No.) : TWI, SWF, SWC_F, PAS SERIES
收件日期(Sample Receiving Date) : 2013/12/30
測試期間(Testing Period) : 2013/12/30 TO 2014/01/07

測試結果(Test Results) : 請見下一頁 (Please refer to next pages).


Troy Chang / Manager Tech
Signed for and on behalf of
SGS TAIWAN LTD.
Chemical Laboratory - Taipei

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測試結果(Test Results)

測試部位(PART NAME)No.1 : 整體混測 (MIXED ALL PARTS)

測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result)
				No.1
鎘 / Cadmium (Cd)	mg/kg	參考IEC 62321-5: 2013方法, 以感應耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n.d.
鉛 / Lead (Pb)	mg/kg	參考IEC 62321-5: 2013方法, 以感應耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n.d.
汞 / Mercury (Hg)	mg/kg	參考IEC 62321-4: 2013方法, 以感應耦合電漿原子發射光譜儀檢測. / With reference to IEC 62321-4: 2013 and performed by ICP-AES.	2	n.d.
六價鉻 / Hexavalent Chromium Cr(VI)	mg/kg	參考IEC 62321: 2008方法, 以UV-VIS檢測. / With reference to IEC 62321: 2008 and performed by UV-VIS.	2	n.d.

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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result)
				No.1
鄰苯二甲酸甲苯基丁酯 / BBP (Benzyl butyl phthalate) (CAS No.: 85-68-7)	%	參考EN 14372, 以氣相層析/質譜儀檢測之。 / With reference to EN 14372. Analysis was performed by GC/MS.	0.003	n.d.
鄰苯二甲酸二(2-乙基己基)酯 / DEHP (Di-(2-ethylhexyl) phthalate) (CAS No.: 117-81-7)	%	參考EN 14372, 以氣相層析/質譜儀檢測之。 / With reference to EN 14372. Analysis was performed by GC/MS.	0.003	n.d.
鄰苯二甲酸二異癸酯 / DIDP (Di- isodecyl phthalate) (CAS No.: 26761-40-0; 68515-49-1)	%	參考EN 14372, 以氣相層析/質譜儀檢測之。 / With reference to EN 14372. Analysis was performed by GC/MS.	0.01	n.d.
鄰苯二甲酸二異壬酯 / DINP (Di- isononyl phthalate) (CAS No.: 28553-12-0; 68515-48-0)	%	參考EN 14372, 以氣相層析/質譜儀檢測之。 / With reference to EN 14372. Analysis was performed by GC/MS.	0.01	n.d.
鄰苯二甲酸二正辛酯 / DNOP (Di-n- octyl phthalate) (CAS No.: 117- 84-0)	%	參考EN 14372, 以氣相層析/質譜儀檢測之。 / With reference to EN 14372. Analysis was performed by GC/MS.	0.003	n.d.
鄰苯二甲酸二丁酯 / DBP (Dibutyl phthalate) (CAS No.: 84-74-2)	%	參考EN 14372, 以氣相層析/質譜儀檢測之。 / With reference to EN 14372. Analysis was performed by GC/MS.	0.003	n.d.
鄰苯二甲酸二異丁酯 / DIBP (Di- isobutyl phthalate) (CAS No.: 84- 69-5)	%	參考EN 14372, 以氣相層析/質譜儀檢測之。 / With reference to EN 14372. Analysis was performed by GC/MS.	0.003	n.d.

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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result)
				No.1
六溴環十二烷及所有主要被辨別出的異構物 / Hexabromocyclododecane (HBCDD) and all major diastereoisomers identified (α -HBCDD, β -HBCDD, γ -HBCDD) (CAS No.: 25637-99-4 and 3194-55-6 (134237-51-7, 134237-50-6, 134237-52-8))	mg/kg	參考IEC 62321: 2008方法, 以氣相層析/質譜儀檢測. / With reference to IEC 62321: 2008 method. Analysis was performed by GC/MS.	5	n.d.
多溴聯苯總和 / Sum of PBBs	mg/kg	參考IEC 62321: 2008方法, 以氣相層析/質譜儀檢測. / With reference to IEC 62321: 2008 and performed by GC/MS.	-	n.d.
一溴聯苯 / Monobromobiphenyl	mg/kg		5	n.d.
二溴聯苯 / Dibromobiphenyl	mg/kg		5	n.d.
三溴聯苯 / Tribromobiphenyl	mg/kg		5	n.d.
四溴聯苯 / Tetrabromobiphenyl	mg/kg		5	n.d.
五溴聯苯 / Pentabromobiphenyl	mg/kg		5	n.d.
六溴聯苯 / Hexabromobiphenyl	mg/kg		5	n.d.
七溴聯苯 / Heptabromobiphenyl	mg/kg		5	n.d.
八溴聯苯 / Octabromobiphenyl	mg/kg		5	n.d.
九溴聯苯 / Nonabromobiphenyl	mg/kg		5	n.d.
十溴聯苯 / Decabromobiphenyl	mg/kg	5	n.d.	

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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result)
				No.1
多溴聯苯醚總和 / Sum of PBDEs	mg/kg	參考IEC 62321: 2008方法, 以氣相層析/質譜儀檢測. / With reference to IEC 62321: 2008 and performed by GC/MS.	-	n.d.
一溴聯苯醚 / Monobromodiphenyl ether	mg/kg		5	n.d.
二溴聯苯醚 / Dibromodiphenyl ether	mg/kg		5	n.d.
三溴聯苯醚 / Tribromodiphenyl ether	mg/kg		5	n.d.
四溴聯苯醚 / Tetrabromodiphenyl ether	mg/kg		5	n.d.
五溴聯苯醚 / Pentabromodiphenyl ether	mg/kg		5	n.d.
六溴聯苯醚 / Hexabromodiphenyl ether	mg/kg		5	n.d.
七溴聯苯醚 / Heptabromodiphenyl ether	mg/kg		5	n.d.
八溴聯苯醚 / Octabromodiphenyl ether	mg/kg		5	n.d.
九溴聯苯醚 / Nonabromodiphenyl ether	mg/kg		5	n.d.
十溴聯苯醚 / Decabromodiphenyl ether	mg/kg	5	n.d.	
鹵素 / Halogen				
鹵素 (氟) / Halogen-Fluorine (F) (CAS No.: 14762-94-8)	mg/kg	參考BS EN 14582:2007, 以離子層析儀分析. / With reference to BS EN 14582:2007. Analysis was performed by IC.	50	n.d.
鹵素 (氯) / Halogen-Chlorine (Cl) (CAS No.: 22537-15-1)	mg/kg		50	n.d.
鹵素 (溴) / Halogen-Bromine (Br) (CAS No.: 10097-32-2)	mg/kg		50	n.d.
鹵素 (碘) / Halogen-Iodine (I) (CAS No.: 14362-44-8)	mg/kg		50	n.d.

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備註(Note) :

1. mg/kg = ppm ; 0.1wt% = 1000ppm
2. n.d. = Not Detected (未檢出)
3. MDL = Method Detection Limit (方法偵測極限值)
4. "-" = Not Regulated (無規格值)
5. 樣品的測試是基於申請人要求混合測試，報告中的混合測試結果不代表其中個別單一材質的含量。(The samples was/were analyzed on behalf of the applicant as mixing sample in one testing. The above results was/were only given as the informality value.)

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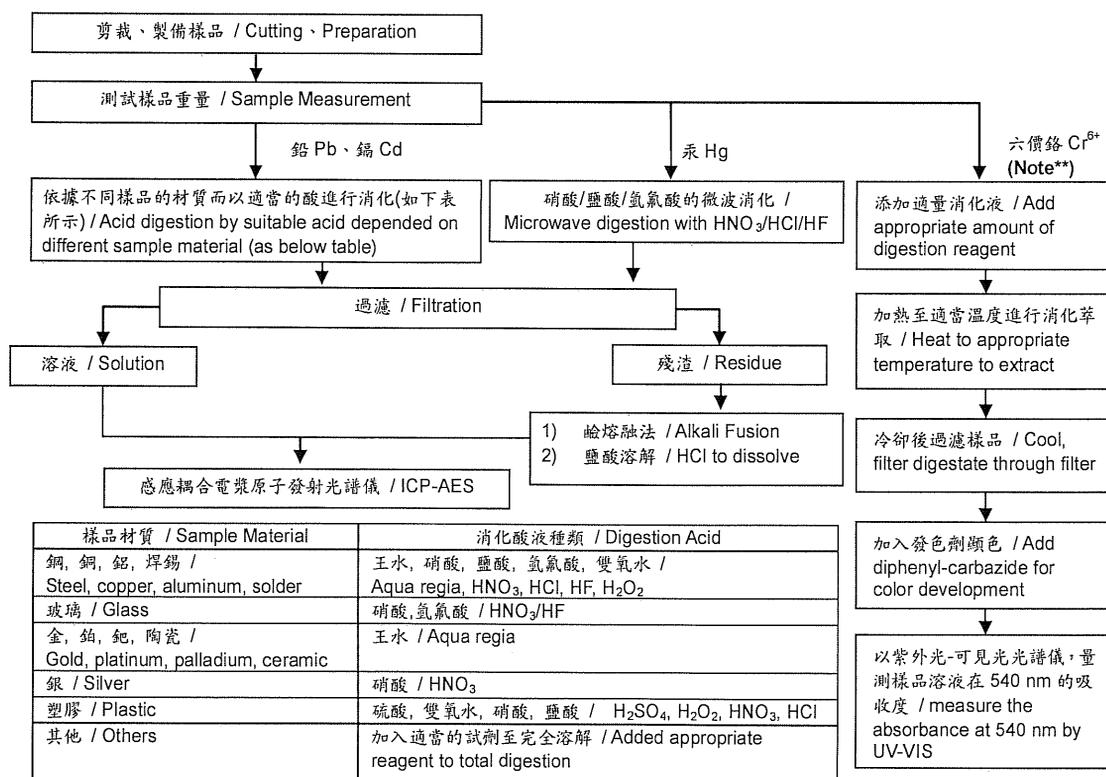
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- 1) 根據以下的流程圖之條件，樣品已完全溶解。(六價鉻測試方法除外) / These samples were dissolved totally by pre-conditioning method according to below flow chart. (Cr⁶⁺ test method excluded)
- 2) 測試人員：楊登偉 / Name of the person who made measurement: Climbgreat Yang
- 3) 測試負責人：張啓興 / Name of the person in charge of measurement: Troy Chang



Note** (For IEC 62321)

- (1) 針對非金屬材料加入鹼性消化液，加熱至 90-95°C 萃取。 / For non-metallic material, add alkaline digestion reagent and heat to 90-95 °C.
- (2) 針對金屬材料加入純水，加熱至沸騰萃取。 / For metallic material, add pure water and heat to boiling.

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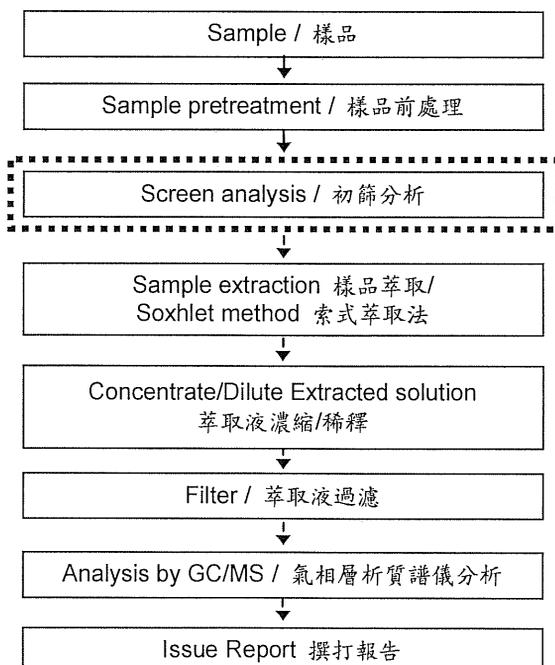
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多溴聯苯/多溴聯苯醚分析流程圖 / PBB/PBDE analytical FLOW CHART

- 測試人員：翁賜彬 / Name of the person who made measurement: Roman Wong
- 測試負責人：張啓興 / Name of the person in charge of measurement: Troy Chang

初次測試程序 / First testing process —————>
 選擇性篩檢程序 / Optional screen process
 確認程序 / Confirmation process - - - ->



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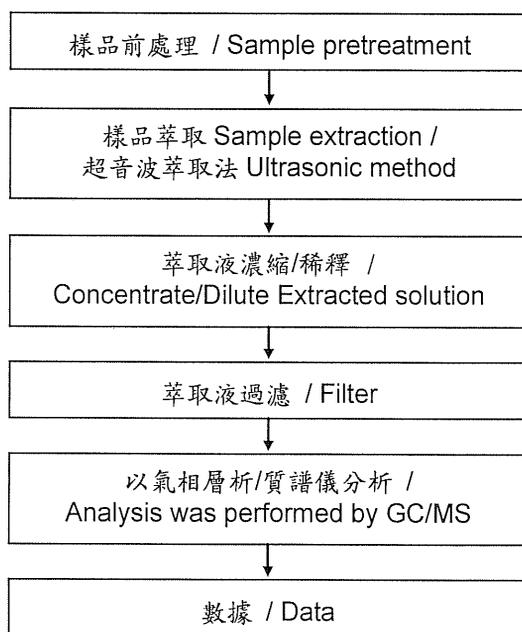
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六溴環十二烷分析流程圖 / HBCDD analytical flow chart

- 測試人員：翁賜彬 / Name of the person who made measurement: Roman Wong
- 測試負責人：張啓興 / Name of the person in charge of measurement: Troy Chang



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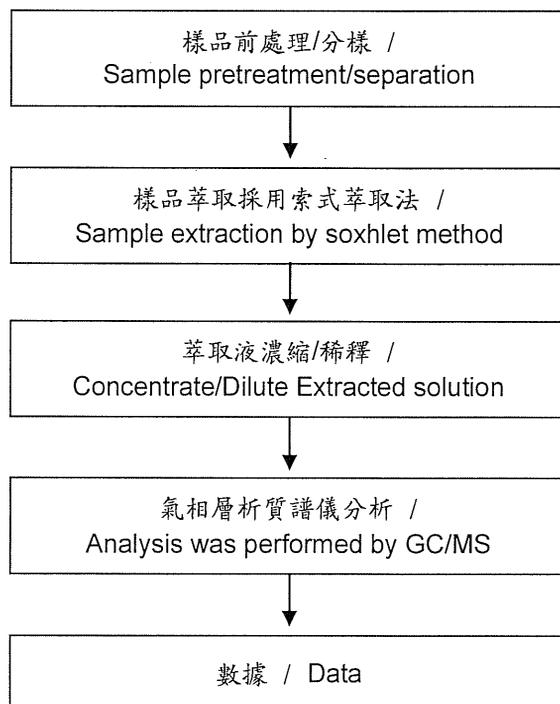
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可塑劑分析流程圖 / Analytical flow chart of phthalate content

- 測試人員：翁賜彬 / Name of the person who made measurement: Roman Wong
- 測試負責人：張啓興 / Name of the person in charge of measurement: Troy Chang



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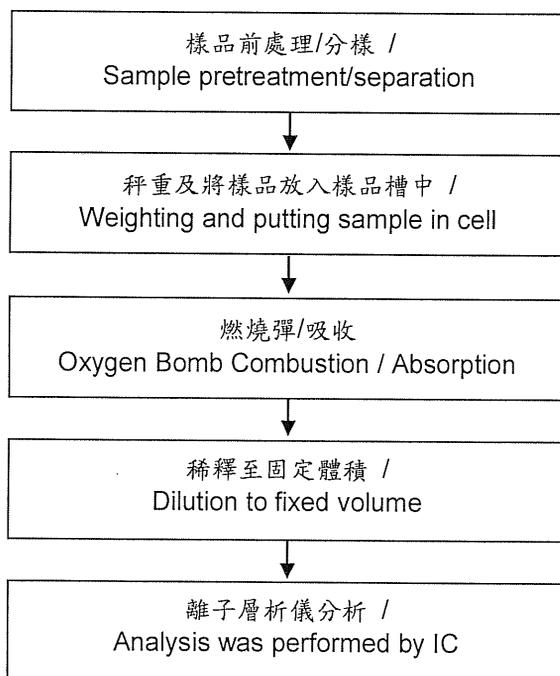
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鹵素分析流程圖 / Analytical flow chart of halogen content

- 測試人員：陳恩臻 / Name of the person who made measurement: Rita Chen
- 測試負責人：張啓興 / Name of the person in charge of measurement: Troy Chang



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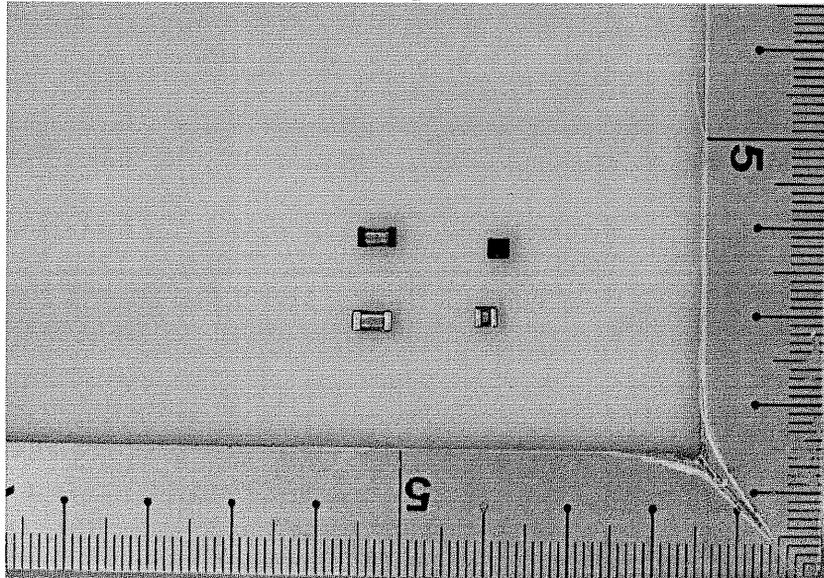
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* 照片中如有箭頭標示，則表示為實際檢測之樣品/部位。*

(The tested sample / part is marked by an arrow if it's shown on the photo.)

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** 報告結尾 (End of Report) **